Structured Electronic Design

- ET 8016
- 5 ECTS credits



Structured Electronic Design

Some keywords:

- Design methodology
- Analysis and Synthesis
- Applied network theory
- · Fundamental research
- Free-swinging intellect

An amplifier



- 1. What type of amplifier is this?
- 2. When the gain is 10, what is the value of R_1 ?

Another amplifier



3. When the gain is 100, what is the value of R_2 ?

And another amplifier



4. When the gain is 2, what is the value of R_3 ?

And another...



5. When the gain is 20, what is the value of R_4 ?





Fundamental research



• How to design an amplifier? (techniques)

• *Why* do it this way? (philosophy)





7. What is this?



8. Will the lamp light up?



9. Will the lamp light up?







YES

NO

Platonic solids



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10.1s this a good model?



It correctly predicts the orbit of all planets you can see with the naked eye.

Modeling

A correct model gives a correct prediction



Platonic solids



"The five Pythagorean regular polyhedra dictate the structure of the universe and reflect God's plan through geometry"; June19, 1595, Johannes Kepler







Dodecahedron

Icosahedron

Modeling

A correct model gives a correct prediction



Never confuse models with "the truth"

Back to the amplifier...



6. What is the current through the load?



Design problems arise from bad formulations

Ludwig Wittgenstein(1889-1951

Amplifier design



An amplifier with a nullor



Nullor



Input current and input voltage of the nullor are made zero by the output signals of the nullor

Inside the Nullor



Input current and input voltage of the nullor are made zero by the output signals of the nullor

What is the transfer *T* of this amplifier?



The transfer T of this amplifier



Another transfer T of this amplifier



Joseph Henry



The seeds of great discovery are constantly floating around us, but they only take root in minds well prepared to receive them

The chain matrix of this amplifier



The two-port and its chain matrix



The two-port and its chain matrix





Nullor



Input current and input voltage of the nullor are made zero via the output signals of the nullor

$$\begin{pmatrix} v_{in} \\ i_{in} \end{pmatrix} = \begin{pmatrix} 0 & 0 \\ 0 & 0 \end{pmatrix} \begin{pmatrix} v_{out} \\ i_{out} \end{pmatrix}$$

Accurate amplification

Information from source to load

- Signal power is enlarged
- Information stays unaltered



A,*B*,*C*,*D* constant *A*,*B*,*C*,*D* accurately known

A voltage-to-voltage amplifier



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Amplification factor becomes inaccurate.



$$A_{v} = -\frac{R_{2}}{R_{1} + R_{s}}$$
$$S_{v_{n}} = 4kT(R_{1} + R_{s}) //R_{2}$$

Information is disturbed Amplification factor still inaccurate.

Change topology





Orthogonalization



Optimization





Right choice

Orthogonalization

Optimization



The "right" choice:

- Start? (as usual?)
- Analyze?
- Optimize?
- Orthogonality?
- Specifications?
- Criteria?

The criteria

$$C = B^{2} \log \frac{S + N}{N}$$

- 1. Noise
- 2. Signal power (distortion)
- 3. Bandwidth

And what about supply voltage, current, power consumption, technology etc.?

Correlated properties

- 1. Noise
- 2. Signal power (distortion)
- Optimization
- 3. Bandwidth

Orthogonalization

Orthogonal properties (2)

- Properties are generally not orthogonal
- But design as if
- Make it right



As if...

When optimizing bandwidth:

- Small-signal models (no non-linearity)
- No noise

When optimizing noise behavior:

- Small-signal models (no non-linearity)
- No bandwidth details

When optimizing non-linear behavior (distortion):

- No dynamic effects
- No noise

bandwidth – noise – distortion bandwidth – distortion - noise noise - bandwidth – distortion noise – distortion - bandwidth distortion - noise – bandwidth distortion – bandwidth - noise Know which problem to solve first



- Is it green?
- Is it an animal?

See the structure: Create Hierarchy!



Efficient design

- The right design step at the right time
- A design step occurs only once

Orthogonality, hierarchy, classification

Efficient design (2)

Reduce the search space as fast as possible.

Look for "fast" criteria:

• Necessary but not sufficient (e.g. *LP*-product)

Extensive calculations only when it "makes sense"

• Simplest model that suffices

Attitude

- Know exactly what you want
- Use second best, if you can't have it
- *Know* the penalty

Voltage amplifier, what's in the nullor?



Inside the Nullor



Nullator? Norrator?



practical nullor implementations



Choose



The experts with practical experience...





Loopgain with B-type block



Loopgain with A-type block



Which transistor stage?



Voltage amplifier with A-type block



Back to the B-type solution (told you so....)



The "expert" solution



"Expert" versus "logic"



Which solution when?



Alternatives

TEXAS INSTRUMENTS www.ti.com



TPA2013D1 SLOS520-AUGUST 2007

2.7-W CONSTANT OUTPUT POWER CLASS-D AUDIO AMPLIFIER WITH INTEGRATED BOOST CONVERTER

FEATURES

- · High Efficiency Integrated Boost Converter (Over 90% Efficiency)
- 2.2-W into an 8-Ω Load from a 3.6-V Supply
- 2.7-W into an 4-Ω Load from a 3.6-V Supply
- Operates from 1.8 V to 5.5 V
- · Efficient Class-D Prolongs Battery Life
- · Independent Shutdown for Boost Converter and Class-D Amplifier
- Differential Inputs Reduce RF Common Noise Built-in INPUT Low Pass Filter Decreases RF
- and Out of Band Noise Sensitivity
- Synchronized Boost and Class-D Eliminates Beat Frequencies
- Thermal and Short-Circuit Protection
- Available in 2.275 mm x 2.275 mm 16-ball WCSP and 4 mm x 4 mm 20-Lead QFN Packages
- 3 Selectable Gain Settings of 2 V/V, 6 V/V, and 10 V/V

APPLICATIONS Cell Phones

- PDA
- GPS
- Portable Electronics

DESCRIPTION

The TPA2013D1 is a high efficiency Class-D audio power amplifier with an integrated boost converter. It drives up to 2.7 W (10% THD+N) into a 4 Ω speaker. With 85% typical efficiency, the TPA2013D1 helps extend battery life when playing audio.

The built-in boost converter generates the voltage rail for the Class-D amplifier. This provides a louder audio output than a stand-alone amplifier connected directly to the battery. It also maintains a consistent loudness, regardless of battery voltage. Additionally, the boost converter can be used to supply external devices.

The TPA2013D1 has an integrated low pass filter to improve RF rejection and reduce out-of-band noise, increasing the signal to noise ratio (SNR). A built-in PLL synchronizes the boost converter and Class-D switching frequencies, thus eliminating beat frequencies and improving audio quality. All outputs are fully protected against shorts to ground, power supply, and output-to-output shorts.



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CLASS D AMPLIFIER DC CHARACTERISTICS

T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CMR	Input common mode range	V_{in} = ±100 mV, V_{DD} = 1.8 V, V_{CC} = 3 V, R_L = 8 Ω	0.5		2.2	v
		V_{In} = ±100 mV, V_{DD} = 2.5 V, V_{CC} = 3.6 V, R_{L} = 8 Ω	0.5		2.8	
		V_{in} = ±100 mV, V_{DD} = 3.6 V, V_{CC} = 5.5 V, R_L = 8 Ω	0.5		4.7	
CMRR	Input common mode rejection	R_L = 8 Ω,V_{lcm} = 0.5 and V_{lcm} = V_{CC} – 0.8, differential inputs shorted		-75		dB
Voo	Output offset voltage Class-D	V_{CC} = 3.6 V, Av = 2 V/V, IN+ = IN- = V_{ref} , R _L = 8 Ω		1	6	mV
		V_{CC} = 3.6 V, Av = 6 V/V, IN+ = IN- = V_{ref} , R _L = 8 Ω		1	6	
		$V_{\text{CC}}\text{=}$ 3.6 V, Av = 10 V/V, IN+ = IN- = $V_{\text{ref}},\text{R}_{\text{L}}$ = 8 Ω		1	6	
		V_{CC} = 5.5 V, Av = 2 V/V, IN+ = IN- = V_{ref} R $_{\text{L}}$ = 8 Ω		1	6	
Rin	Input Impedance	Gain = 2 V/V (6 dB)		32		kΩ
		Gain = 6 V/V (15.5 dB)		15		
		Gain = 10 V/V (20 dB)		9.5		
R _{DB(an)}	OUTP High-side FET On-state series resistance	I _{OUTx} = -300 mA; V _{CC} = 3.6 V		0.36		
	OUTP Low-side FET On-state series resistance			0.36		
R _{DS(an)}	OUTN High-side FET On-state series resistance			0.36		
	OUTN Low-side FET On-state series resistance			0.36		
Av	Low Gain	GAIN ≤ 0.35 V	1.8	2	2.2	V/V
	Mid Gain	GAIN = 0.8 V	5.7	6	6.3	V/V
	High Gain	GAIN ≥ 1.35 V	9.5	10	10.5	V/V



Conclusions

- Know ideal case
- Know the penalty for choosing second best
- Beware of experts !
- Always remember the ideal case!



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